

STPS40L15C

Low drop OR-ing power Schottky diode

Features

- Very low forward voltage drop for less power dissipation and reduced heatsink size
- Reverse voltage suited to OR-ing of 3 V, 5 V and 12 V rails
- Avalanche capability specified

Description

Dual center tap schottky rectifier packaged in TO-220AB and TO-247, this device is especially intended for use as OR-ing diode in fault tolerant power supply equipments.

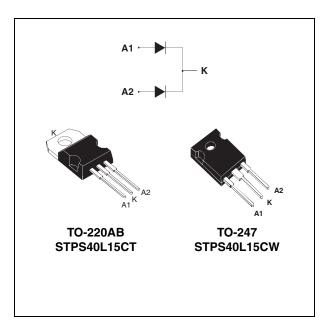


Table 1.Device summary

Symbol	Value
I _{F(AV)}	2x20 A
V _{RRM}	15 V
T _{j (max)}	125 °C
V _{F (max)}	0.33 V

1 Characteristics

Symbol	Parame	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage	15	V		
I _{F(RMS)}	Forward current rms			30	А
1	$T_{case} = 140 \circ C$ Total		40	۸	
I _{F(AV)}	Average forward current	$\delta = 1$	Per diode	20	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 m, Sinus	oidal	310	А
I _{RRM}	Peak repetitive reverse current	t _p = 2 μs, F= 1 k	Hz	2	А
I _{RSM}	Non repetitive peak reverse current	t _p = 100 μs		3	А
P _{ARM}	Repetitive peak avalanche power	lanche power $t_p = 1 \mu s, T_j = 25 \degree C$			W
T _{stg}	Storage temperature range	-65 to + 150	°C		
Тj	Maximum operating junction temper	125	°C		
dV/dt	Critical rate of rise of reverse voltag	10000	V/µs		

Table 2. Absolute ratings (limiting values, per diode)

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

Symbol	Parameter	Value	Unit	
D	Junction to case	Per diode	1.6	°C/W
R _{th(j-c)}	Ath(j-c) Junction to case		0.85	0/00
R _{th (c)}	Coupling		0.1	°C/W

Table 4. Static electrical characteristics (Per diode)

Symbol	Parameter	Tests co	Min.	Тур.	Max.	Unit	
I _B ⁽¹⁾	Reverse leakage	T _j = 25 °C	V _ V			6	mA
'R`´	current	T _j = 100 °C	$V_{\rm R} = V_{\rm RRM}$		200	500	ША
		T _j = 25 °C	I _F = 19 A			0.41	
V _F ⁽¹⁾	V (1) Forward valtage drag	T _j = 25 °C	I _F = 40 A			0.52	V
VF	Forward voltage drop	T _j = 125 °C	I _F = 19 A 0	0.28	0.33	v	
		T _j = 125 °C	I _F = 40 A		0.42	0.50	

1. Pulse test : t_p = 380 µs, δ < 2%

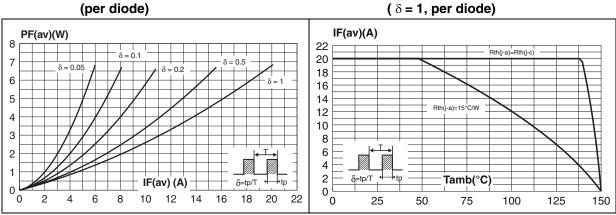
To evaluate the conduction losses use the following equation : P = 0.18 x $I_{F(AV)}$ + 0.008 $I_{F}^{2}(RMS)$



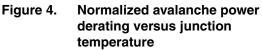
Average forward current versus

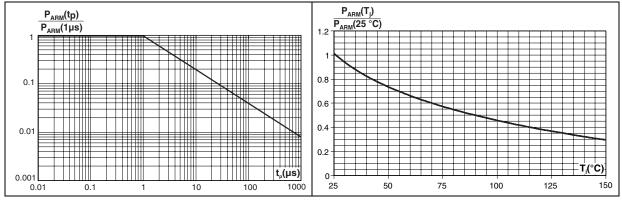
ambient temperature

Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)

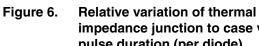


Normalized avalanche power Figure 3. derating versus pulse duration

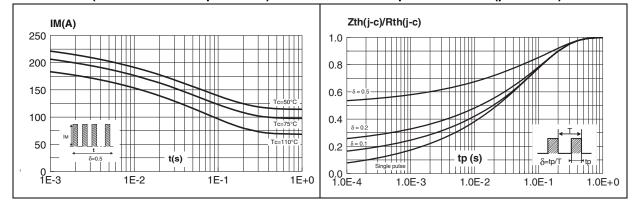




Non repetitive surge peak forward Figure 5. current versus overload duration (maximum values per diode)



impedance junction to case versus pulse duration (per diode)



F=1MHz

Tj=25°C

10

20

Figure 7. Reverse leakage current versus reverse voltage applied (typical values per diode)

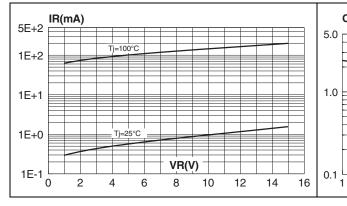


Figure 9. Forward voltage drop versus forward current (typical values per diode)

Figure 10. Forward voltage drop versus forward current (typical maximum per diode)

VR(V)

5

2

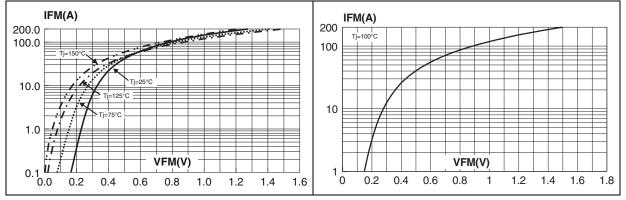


Figure 8.

C(nF)

values per diode)

Junction capacitance versus

reverse voltage applied (typical

2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque values for: TO-220AB 0.4 to 0.6 N·m
- Recommended torque values for: TO-247 0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB dimensions

		Dimensions			
	Ref.	Millimeters		Inches	
		Min.	Max.	Min.	Max.
	A	4.40	4.60	0.173	0.181
	С	1.23	1.32	0.048	0.106
H2 A	D	2.40	2.72	0.094	0.009
	E	0.49	0.70	0.019	0.037
	F	0.61	0.88	0.024	0.067
	F1	1.14	1.70	0.044	0.024
	F2	1.14	1.70	0.044	0.054
	G	4.95	5.15	0.194	0.368
	G1	2.40	2.70	0.094	0.409
L4	H2	10	10.40	0.393	0.208
	L2	16.4 typ		0.645 typ	
	L4	13	14	0.511	0.055
G	L5	2.65	2.95	0.104	0.069
	L6	15.25	15.75	0.600	0.126
	L7	6.20	6.60	0.244	
	L9	3.50	3.93	0.137	
	М	2.6	typ.	0.10	2 typ.
	Diam.	3.75	3.85	0.147	0.151



				Dimer	nsions		
	Ref.	M	illimete	rs		Inches	
		Min.	Тур.	Max.	Min.	Тур.	Max.
	А	4.85		5.15	0.191		0.203
	D	2.20		2.60	0.086		0.031
	E	0.40		0.80	0.015	0.009	
	F	1.00		1.40	0.039		0.055
	F1		3.00			0.118	
	F2		2.00			0.078	
	F3	2.00		2.40	0.078		0.094
	F4	3.00		3.40	0.118		0.133
	G		10.90			0.429	
	Н	15.45		15.75	0.608		0.620
	L	19.85		20.15	0.781		0.793
	L1	3.70		4.30	0.145		0.169
V_2 F_4 L_3 $\rightarrow D_4$	L2		18.50			0.728	
F(x3)	L3	14.20		14.80	0.559		0.582
	L4		34.60			1.362	
	L5		5.50			0.216	
	М	2.00		3.00	0.078		0.118
	V		5°			5°	
	V2		60°			60°	
	Dia	3.55		3.65	0.139		0.143

Table 6. TO-247 dimensions



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS40L15CW	STPS40L15CW	TO-247	4.4 g	30	Tube
STPS40L15CT	STPS40L15CT	TO-220AB	2.2 g	50	Tube

4 Revision history

Table 8.Document revision history

Date	Revision	Changes			
July-2003	5A	Previous edition.			
18-Jul-2011	6	Added cathode indicator K to illustration for TO-220AB.			



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